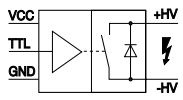
FAST HIGH VOLTAGE TRANSISTOR SWITCHES

These MOSFET switches are designed for general high voltage switching applications such as pockels cell drivers, deflection and acceleration grid drivers, piezo drivers and MCP/SEV pulsers. The switching modules incorporate all features of the well known HTS switch family: Easy handling, high reliability, low jitter and reproducible switching behaviour.

Due to its very low coupling capacitance (switch against control) the series HTS-LC is preferred especially in applications with higher operating frequencies and in case of increased EMC requirements. HTS-LC switches provide significant advantages regarding noise immunity especially at high dv/dt's and may simplify critical circuit designs under EMC and EMI aspects. But for technical reasons there are some limitations in application circuits with HV transients to be expected across an opened switch (e.g. in push-pull circuits with two or more switches). Please consult factory in such cases.

The controlled turn-on will be achieved by a positive going signal of 3 to 10 volts amplitude, provided the switch is permanently connected to the +5.00 VDC auxiliary supply. The on-time may simply be varied between 200 ns and infinity by the input control pulse width. An interference-proof driver circuit provides signal conditioning, auxiliary voltage monitoring, frequency limitation and temperature protection. In case of any false operating condition the switches turn off immediately and a fault signal is generated (TTL level). The high frequency burst operation (>10 pulses/100μs) requires option 01 (external buffer capacitors). Due to the high galvanic isolation the switches may simply be operated also in floating circuits or high-side switching applications. Several housing options are available to meet individual requirements. The standard plastic case with pigtails is the cost-effective package in low frequency applications with low average power dissipation. The plastic modules can additionally be fitted with non-isolated cooling fins (option 04), which improve the max. continuous power dissipation Pd(max) by approx. the factor 10 with forced air (>4m/s) or up to the factor 50 in oil (e.g. Silicone oil AK50 @ 50°C, flow rate >0.1m/s). With option 06 the modules can be installed also on a printed circuit board, provided additional insulation measures are taken (silicone rubber sealant or oil immersion). Potential free metal housings for a Pd(max) of 1~2 kW are available as option 05 (cf. separate data sheet "High Power Metal Case"). For detailed design recommendations please refer to the general instructions.

HTS 331-03-LC 33 kV / 30A
HTS 501-03-LC 50 kV / 30A
HTS 651-03-LC 65 kV / 30A

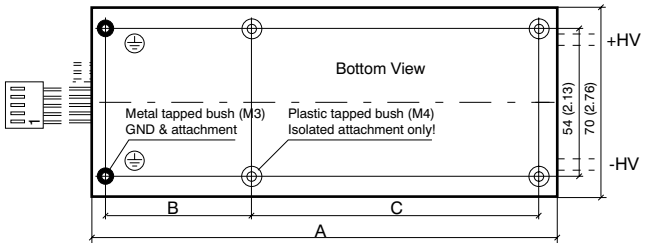


HTS 331-03-LC
(Standard)

- Patented -
Made in Germany

MOSFET TECHNOLOGY

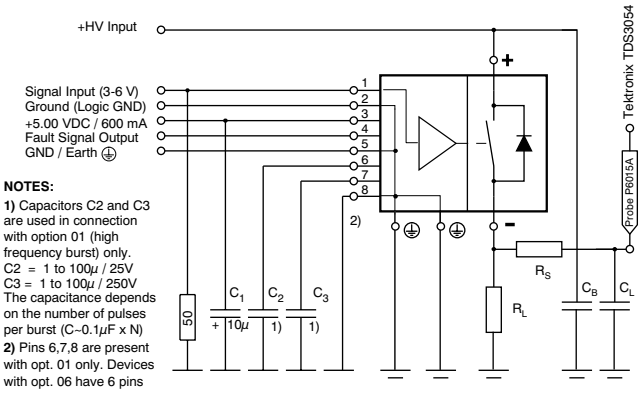
Variable On-Time
Low Coupling Capacitance
Very Compact & Light Weight



	331-03-LC	501-03-LC	651-03-LC
A	200 (7.87)	260 (10.4)	300 (11.81)
B	56 (2.2)	80 (3.15)	80 (3.15)
C	134(5.28)	154 (6.06)	195 (7.68)

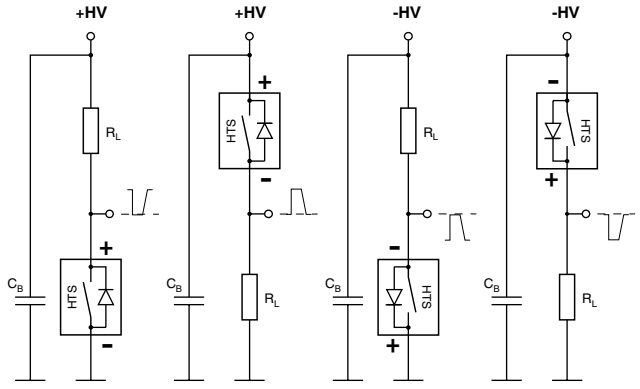
All dimensions in mm and (inches). Metric screws are included in delivery.
Customized cases on request.

Test Circuit (High-Side Switch)



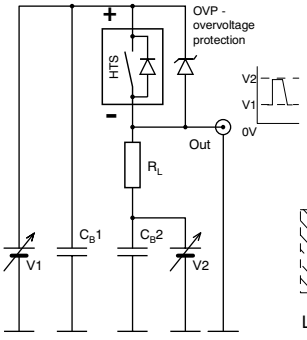
NOTES:
1) Capacitors C2 and C3 are used in connection with option 01 (high frequency burst) only.
C2 = 1 to 100μ / 25V
C3 = 1 to 100μ / 250V
The capacitance depends on the number of pulses per burst (C~0.1μF x N)
2) Pins 6,7,8 are present with opt. 01 only. Devices with opt. 06 have 6 pins (only one ground connector)

Basic Circuits



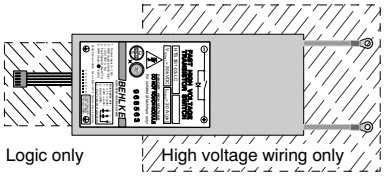
Floating Pulser

V1 must not exceed the Maximum Isolation voltage of the switching module. An OVP is recommended for V1 > Vo(max).



EMC / EMI Design Hints

- Always keep wiring as short as possible
- Avoid induction loops. Peak current carrying forward and return lines should be close together to minimize magnetic fields. Use coaxial lines or apply groundplane designs whenever possible.
- Use shielded or twisted leads for the control connection to minimize noise induction.
- Use low inductance part components only
- Do not "mix" the wiring of the load and the control circuit. Please note the separate wiring areas of logic and HV wiring:



Behlke Electronic GmbH, 61476 Kronberg, Germany, **Tel.** +49 (0) 6173 9290 -20, **Fax** -30, **email** info@behlke.de

TECHNICAL DATA

Specification	Symbol	Condition / Comment		331-03-LC	501-03-LC	651-03-LC	Unit
Maximum Operating Voltage	$V_{O(max)}$	I_{off} < 10 σADC		33	50	65	kVDC
Minimum Operating Voltage	$V_{O(min)}$	Increased $t_{r(on)}$ and $t_{r(off)}$ below 0.1x $V_{O(max)}$			0		kVDC
Typical Breakdown Voltage	V_{br}	I_{off} > 1mADC, T_{case} = 70 °C		36	56	72	kVDC
Galvanic Isolation	V_I	Continuously		50	80	80	kVDC
Maximum Peak Current	$I_{P(max)}$	T_{case} = 25°C	t_p<10 µs, duty cycle <1%		30		
		T_{fin} = 70°C	t_p<100µs, duty cycle <1%		24		
		(In oil also)	t_p<1 ms, duty cycle <1%		17		ADC
Max. Continuous Load Current	I_L	T_{case} = 25°C	Standard plastic case		0.33		
		T_{fin} = 70°C	Opt. 04, cooling fins (Air >4m/s)		0.94		
		(In oil also)	Opt. 04, cooling fins (Oil >0.1m/s)		3.22		ADC
Static On-Resistance	R_{stat}	T_{case} = 25°C	0.1 x $I_{P(max)}$	72	112	144	
			1.0 x $I_{P(max)}$	180	280	360	T
Maximum Off-State Current	I_{off}	0.8 x V_O, T_{case} = 25...70°C			5		σADC
Turn-On Delay Time	$t_{d(on)}$	@ $I_{P(max)}$		150	170	180	ns
Typical Turn-On Rise Time	$t_{r(on)}$	0.8 x V_O, 0.1 x $I_{P(max)}$		15	25	30	ns
Typ. Turn-Off Rise Time (Current)	$t_{r(off)}$	0.8xV_O, 0.1x $I_{P(max)}$, resistive load, 10-90%			10		ns
Minimum On-Time	$t_{on(min)}$	Limited by driver circuit			200		ns
Maximum On-Time	$t_{on(max)}$	Please note possible $P_{d(max)}$ limitations			∞		
Switch Recovery Time	t_{rc}	t_{rc} = minimum pulse spacing			500		ns
Typical Turn-On Jitter	$t_{j(on)}$	V_{aux} / V_{tr} = 5.0 VDC, fixed switching frequency			1		ns
Max. Switching Frequency	$f_{(max)}$	Please note possible $P_{d(max)}$ limitations		5	3	2.5	kHz
Maximum Burst Frequency	$f_{b(max)}$	Use option 01 for >10 pulses within100 µs			2		MHz
Maximum Continuous Power Dissipation	$P_{d(max)}$	T_{case} = 25°C	Standard plastic case (Air)	20	30	36	
		T_{fin} = 70°C	Opt. 04, cooling fins (Air >4m/s)	160	250	320	
		(In oil also)	Opt. 04, cooling fins (Oil >0.1m/s)	1900	2900	3800	Watts
Linear Derating		T_{case} = 25°C	Standard plastic case	0.44	0.66	0.8	
		T_{fin} = 70°C	Opt. 04, cooling fins (Air >4m/s)	3.55	5.55	7.11	
		(In oil also)	Opt. 04, cooling fins (Oil >0.1m/s)	42.22	64.44	84.44	W/K
Temperature Range	T_O	Extended temperature range on request			-40...70		
		With option 03 (Increased thermal conductivity)			-40...85		°C
Natural Capacitance	C_N	Capacitance between switch poles at $V_{O(max)}$		20	25	30	pF
Coupling Capacitance	C_C	HV side against control side		21	30	48	pF
Diode Reverse Recovery Time	t_{rrc}	I_F=0.1x$I_{P(max)}$	MOSFET parasitic diode		500		ns
Diode Forward Voltage Drop	V_F	I_F=0.1x$I_{P(max)}$	MOSFET parasitic diode	27	41	53	VDC
Auxiliary Supply Voltage	V_{aux}	Stabilized to ∂ 5%			5.0		VDC
Auxiliary Supply Current	I_{aux}	@ f_{max}			600		mADC
Control Signal	V_{tr}	> 3VDC recommended			2-10		VDC
Fault Signal Output		TTL compatible, short circuit proof, L=Fault			H= 4 V, L= 0.5 V		VDC
Dimensions	LxWxH	Standard plastic case		200x70x35	260x70x35	300x70x35	
		Flat plastic case (Opt. 06-B)		200x70x19	260x70x19	300x70x19	
		Plastic case + cooling fins		200x70x70	260x70x70	300x70x70	mm^3
Weight		Standard plastic case		700	940	1100	
		Flat plastic case (Opt. 06-B)		410	564	660	
		Plastic case + cooling fins		920	1220	1460	g

Ordering Informations

HTS 331-03-LC Transistor switch, 33 kVDC, 30 Amps.
HTS 501-03-LC Transistor switch, 50 kVDC, 30 Amps.
HTS 651-03-LC Transistor switch, 65 kVDC, 30 Amps.
Option 01 High frequency burst
Option 03 Increased thermal conductivity. Pd(max) will be increased by ~30%. Limited service possibilities in case of damaged modules!
Option 04 Cooling fins, non-isolated for air+oil. Air convection is allowed up to 20 kV. **Above 20 kV oil immersion only!**
Option 05 Metal case, potential-free (Separate data sheet on request)
Option 06 HV bottom terminals for PCB assembly. Additional insulation measures (oil immersion or silicone rubber sealant) required.
Option 06-B Module height 19 mm. Not recommended for operation in air.

Further data and mechanical drawings are available on request. All data and specifications subject to change without notice. 651-03-LC-TB-01-00